

FDG6342L

Integrated Load Switch

Features

- Max $r_{DS(on)}$ = 150mΩ at $V_{GS} = 4.5V$, $I_D = -1.5A$
- Max $r_{DS(on)}$ = 195mΩ at $V_{GS} = 2.5V$, $I_D = -1.3A$
- Max $r_{DS(on)}$ = 280mΩ at $V_{GS} = 1.8V$, $I_D = -1.1A$
- Max $r_{DS(on)}$ = 480mΩ at $V_{GS} = 1.5V$, $I_D = -0.9A$
- Control MOSFET (Q1) includes Zener protection for ESD ruggedness (>4KV Human body model)
- High performance trench technology for extremely low $r_{DS(on)}$
- Compact industry standard SC70-6 surface mount package
- RoHS Compliant

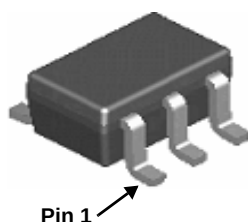


General Description

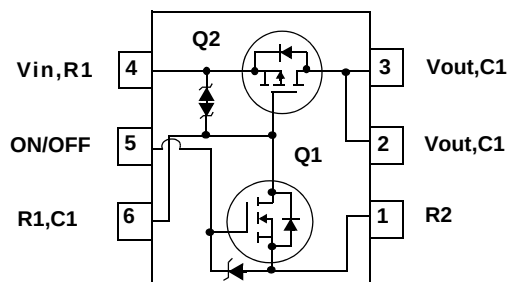
This device is particularly suited for compact power management in portable electronic equipment where 1.5V to 8V input and 1.5A output current capability are needed. This load switch integrates a small N-Channel power MOSFET (Q1) that drives a large P-Channel power MOSFET (Q2) in one tiny SC70-6 package.

Applications

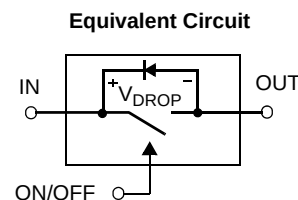
- Power management
- Load switch



SC70-6



See Application Circuit



MOSFET Maximum Ratings $T_A = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{IN}	Gate to Source Voltage (Q2)	± 8	V
$V_{ON/OFF}$	Gate to Source Voltage (Q1)	-0.5 to 8	V
I_{Load}	Load Current -Continuous	(Note 2) -1.5	A
	-Pulsed	(Note 2) -6	
P_D	Power Dissipation for Single Operation	(Note 1a) 0.36	W
		(Note 1b) 0.3	
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ C$

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient Single operation	(Note 1a) 350	$^\circ C/W$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient Single operation	(Note 1b) 415	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.42	FDG6342L	SC70-6	7"	8mm	3000units

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{IN}	V_{IN} Breakdown Voltage	$I_D = -250\mu\text{A}$, $V_{ON/OFF} = 0\text{V}$	8			V
I_{Load}	Zero Gate Voltage Drain Current	$V_{IN} = -6.4\text{V}$, $V_{ON/OFF} = 0\text{V}$			-1	μA
I_{FL}	Leakage Current, Forward	$V_{IN} = 8\text{V}$, $V_{ON/OFF} = 0\text{V}$			10	μA
I_{RL}	Leakage Current, Reverse	$V_{IN} = -8\text{V}$, $V_{ON/OFF} = 0\text{V}$			-10	μA

On Characteristics (note 2)

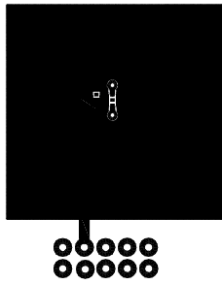
$V_{ON/OFF(th)}$	Gate Threshold Voltage	$V_{IN} = V_{ON/OFF}$, $I_D = -250\mu\text{A}$	0.65	0.8	1.5	V
$r_{DS(on)}$	Static Drain to Source On Resistance (Q2)	$V_{IN} = 4.5\text{V}$, $I_D = -1.5\text{A}$		125	150	$\text{m}\Omega$
		$V_{IN} = 2.5\text{V}$, $I_D = -1.3\text{A}$		150	195	
		$V_{IN} = 1.8\text{V}$, $I_D = -1.1\text{A}$		200	280	
		$V_{IN} = 1.5\text{V}$, $I_D = -0.9\text{A}$		250	480	
		$V_{IN} = 4.5\text{V}$, $I_D = 0.4\text{A}$		2.6	4.0	Ω
	Static Drain to Source On Resistance (Q1)	$V_{IN} = 2.7\text{V}$, $I_D = 0.2\text{A}$		3.3	5.0	

Drain-Source Diode Characteristics

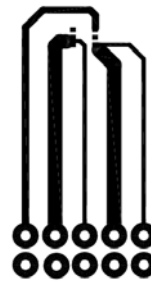
I _S	Maximum Continuous Drain to Source Diode Forward Current				-0.25	V
V _{SD}	Source to Drain Diode Forward Voltage	V _{ON/OFF} = 0V, I _S = -0.25A (Note 2)		-0.6	-1.2	V

NOTES:

1. $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.

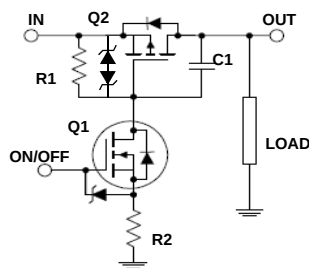


a. 350°C/W when mounted on a 1 in² pad of 2 oz copper.



b. 415°C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300 μs , Duty cycle < 2.0%.

FDG6342L Load Switch Application circuit**External Component Recommendation:**

For additional in-rush current control, R2 and C1 can be added. For more information, see application note AN1030

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

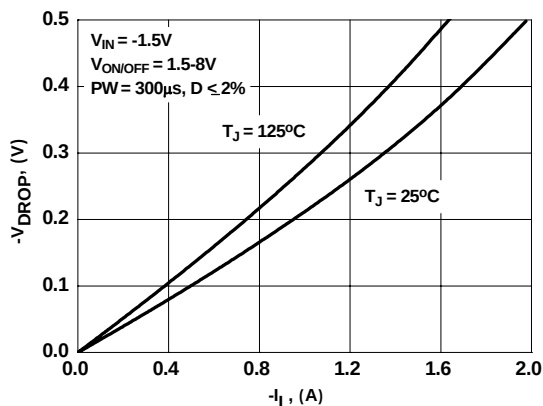


Figure 1. Conduction Voltage Drop Variation with Load Current.

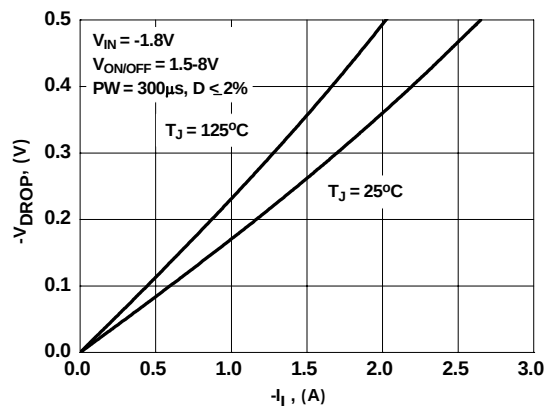


Figure 2. Conduction Voltage Drop Variation with Load Current.

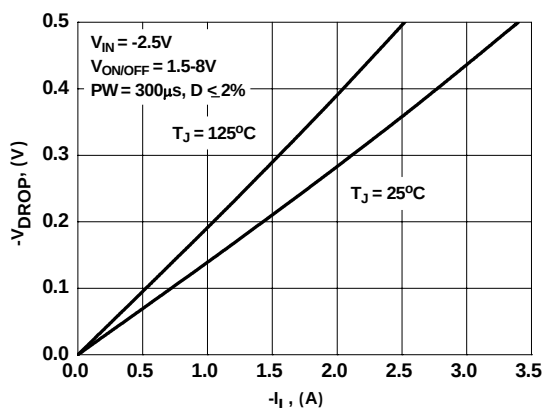


Figure 3. Conduction Voltage Drop Variation with Load Current.

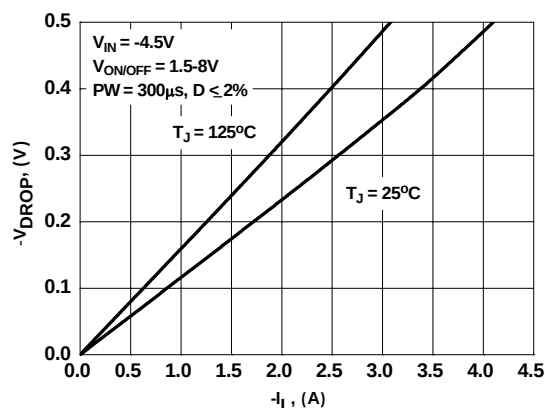


Figure 4. Conduction Voltage Drop Variation with Load Current.

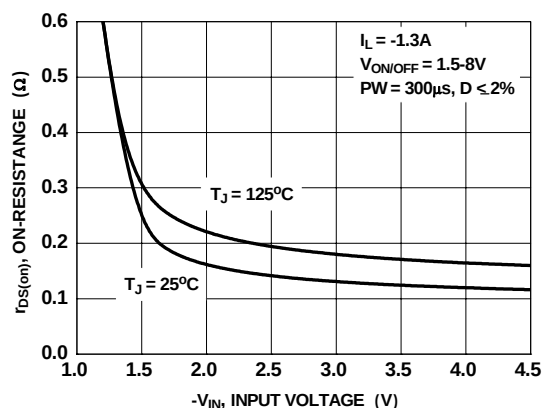


Figure 5. On-Resistance Variation With Input Voltage

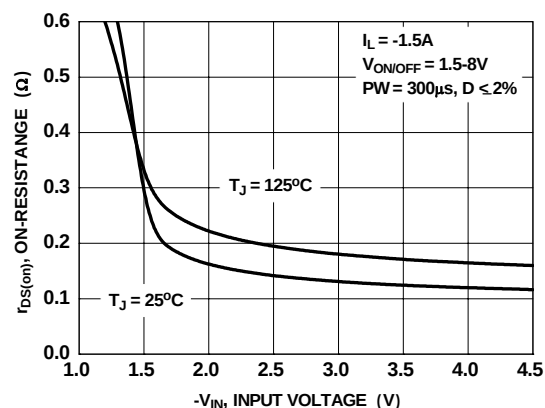


Figure 6. On-Resistance Variation With Input Voltage



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